

TIP31A/31C TIP32A/32B/32C

COMPLEMENTARY SILICON POWER TRANSISTORS

APPLICATION

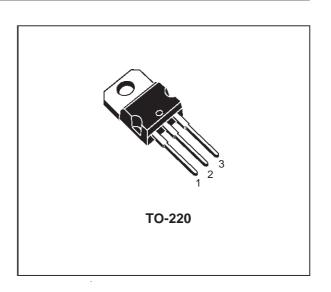
 LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

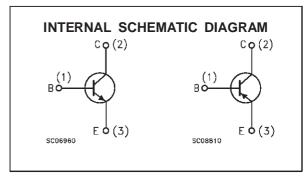
DESCRIPTION

The TIP31A and TIP31C are silicon Epitaxial-Base NPN transistors mounted in Jedec TO-220 plastic package. They are intented for use in medium power linear and switching applications.

The complementary PNP types are TIP32A and TIP32C respectively.

Also TIP32B is a PNP type.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Unit		
		NPN	TIP31A		TIP31C	1
		PNP	TIP32A	TIP32B	TIP32C	1
Vсво	Collector-Base Voltage (I _E = 0)		60	80	100	V
V_{CEO}	Collector-Emitter Voltage (I _B = 0)		60	80	100	V
V_{EBO}	Emitter-Base Voltage (I _C = 0)			5		V
I _C	Collector Current			3		А
I _{CM}	Collector Peak Current			5		А
Ι _Β	Base Current			1		А
P _{tot}	Total Dissipation at T _{case} ≤ 25 °C			40		W
	T _{amb} ≤ 25 °C			2		W
T _{stg}	Storage Temperature			-65 to 150		°C
Tj	Max. Operating Junction Temperature			150		°C

For PNP types voltage and current values are negative

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TIP31A/TIP31C/TIP32A/TIP32B/TIP32C

THERMAL DATA

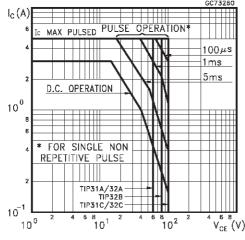
R _{thj-case}	Thermal Resistance Junction-case	Max	3.12	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient	Max	62.5	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

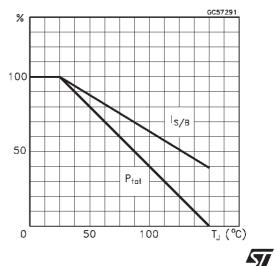
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CEO}	Collector Cut-off Current (I _B = 0)	for TIP31A/32A			0.3 0.3	mA mA
I _{CES}	Collector Cut-off Current (V _{BE} = 0)				0.2 0.2 0.2	mA mA mA
I _{EBO}	Emitter Cut-off Current (Ic = 0)	V _{EB} = 5 V			1	mA
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 30 mA for TIP31A/32A for TIP32B for TIP31C/32C	60 80 100			V V V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$I_C = 3 \text{ A}$ $I_B = 375 \text{ mA}$			1.2	V
V _{BE(on)} *	Base-Emitter Voltage	$I_C = 3 A$ $V_{CE} = 4 V$			1.8	V
h _{FE} *	DC Current Gain	I _C = 1 A	25 10		50	
h _{fe}	Small Signall Current Gain	I _C = 0.5 A V _{CE} = 10 V f = 1 KHz I _C = 0.5 A V _{CE} = 10 V f = 1 MHz	20 3			

Safe Operating Area

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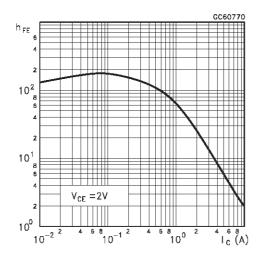


Derating Curves

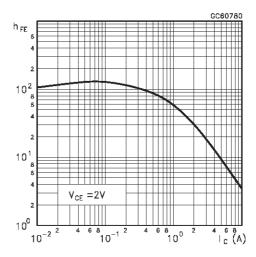


^{*} Pulsed : pulse duration = $300 \,\mu\text{s}$, duty cycle $\leq 2\%$ For PNP types voltage and current values are negative.

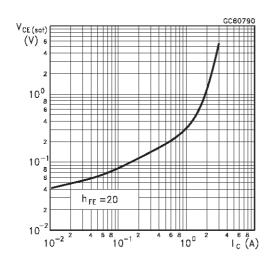
DC Current Gain (NPN type)



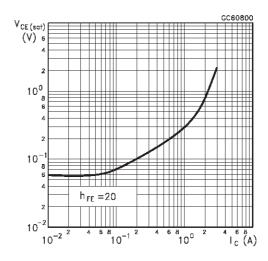
DC Current Gain (PNP type)



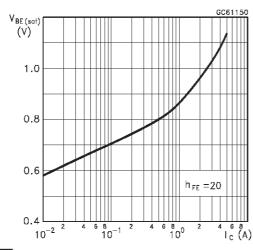
Collector-Emitter Saturation Voltage (NPN type)



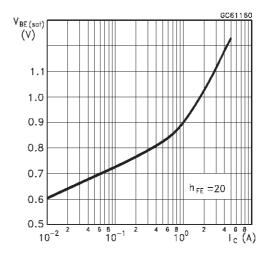
Collector-Emitter Saturation Voltage (PNP type)



Base-Emitter Saturation Voltage (NPN type)



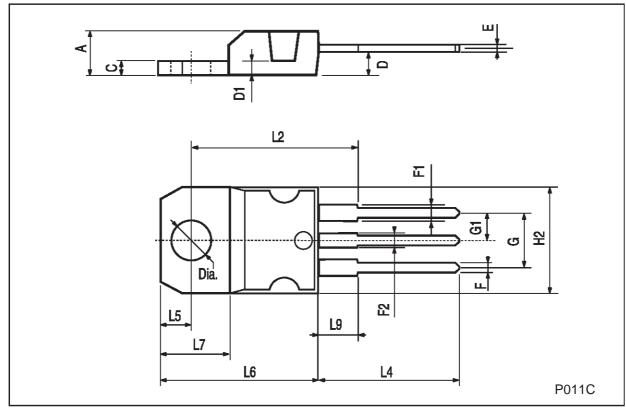
Collector-Base Capacitance (PNP type)



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TO-220 MECHANICAL DATA

DIM.	mm			inch		
שוועו.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
Е	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



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